

SKKD 100, SKMD 100



SEMIPACK® 1

Rectifier Diode Modules

SKKD 100
SKMD 100

Features

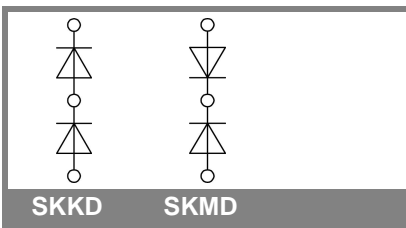
- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- SKKD half bridge connection center-tap connections
- SKMD common cathode
- UL recognized, file no. E 63 532

Typical Applications

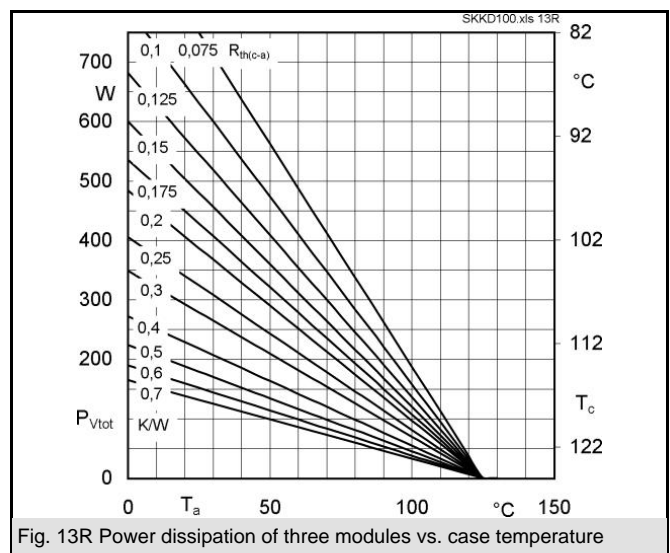
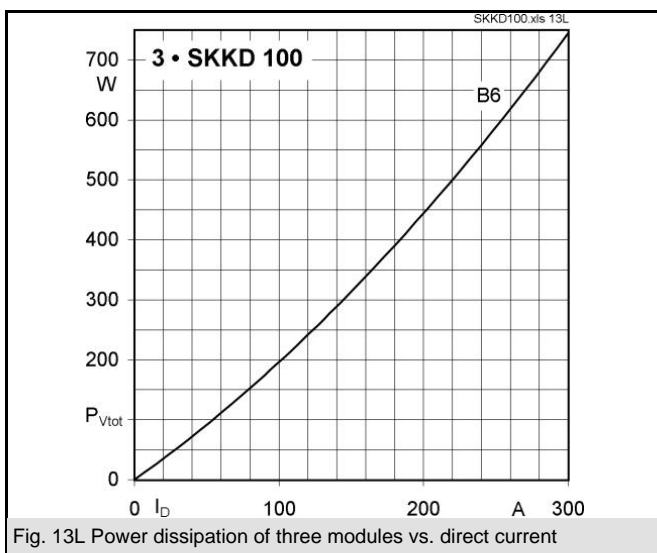
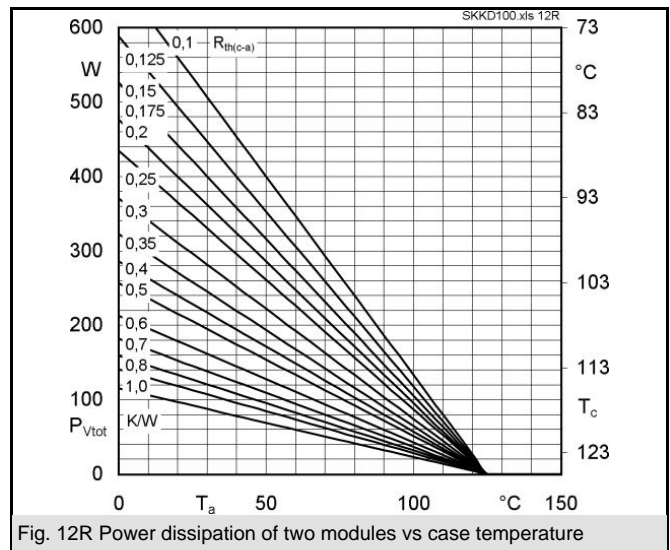
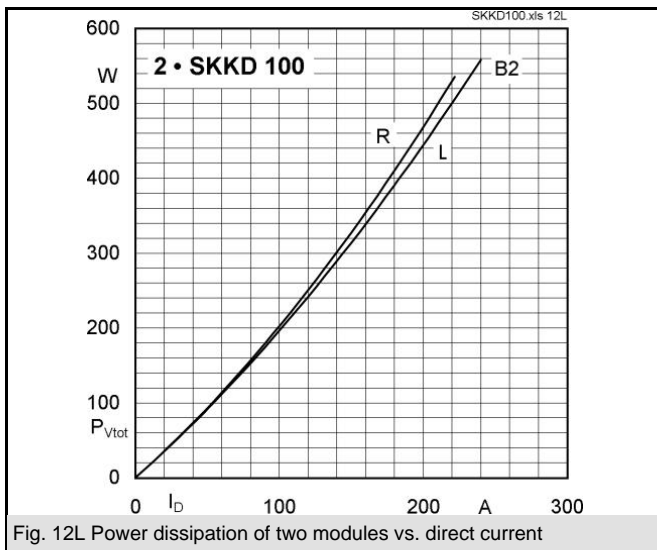
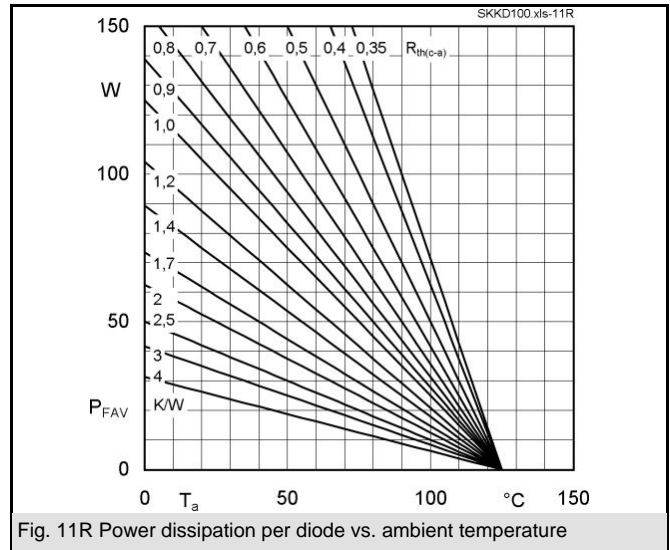
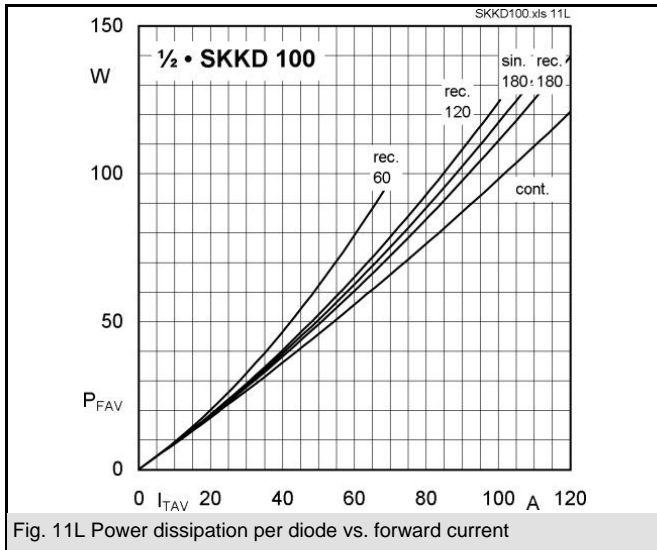
- Non-controllable rectifiers for AC/AC converters
- Line rectifiers for transistorized AC motor controllers
- Field supply for DC motors

V_{RSM} V	V_{RRM} V	$I_{FRMS} = 175$ A (maximum value for continuous operation) $I_{FAV} = 100$ A (sin. 180; $T_c = 85$ °C)	
500	400	SKKD 100/04	SKMD 100/04
900	800	SKKD 100/08	SKMD 100/08
1300	1200	SKKD 100/12	
1500	1400	SKKD 100/14	SKMD 100/14
1700	1600	SKKD 100/16	SKMD 100/16
1900	1800	SKKD 100/18	

Symbol	Conditions	Values	Units
I_{FAV}	sin. 180; $T_c = 85$ (100) °C	100 (67)	A
I_D	P3/180; $T_a = 45$ °C; B2 / B6	73 / 91	A
	P3/180F; $T_a = 35$ °C; B2 / B6	150 / 190	A
I_{FSM}	$T_{vj} = 25$ °C; 10 ms	2500	A
	$T_{vj} = 125$ °C; 10 ms	2000	A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms	31250	A ² s
	$T_{vj} = 125$ °C; 8,3 ... 10 ms	20000	A ² s
V_F	$T_{vj} = 25$ °C; $I_F = 300$ A	max. 1,35	V
$V_{(TO)}$	$T_{vj} = 125$ °C	max. 0,85	V
r_T	$T_{vj} = 125$ °C	max. 1,3	mΩ
I_{RD}	$T_{vj} = 125$ °C; $V_{RD} = V_{RRM}$	max. 5	mA
$R_{th(j-c)}$	per diode / per module	0,35 / 0,175	K/W
$R_{th(c-s)}$	per diode / per module	0,2 / 0,1	K/W
T_{vj}		- 40 ... + 125	°C
T_{stg}		- 40 ... + 125	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 %	Nm
M_t	to terminals	3 ± 15 %	Nm
a		5 * 9,81	m/s ²
m	approx.	95	g
Case	SKKD	A 10	
	SKMD	A 33	



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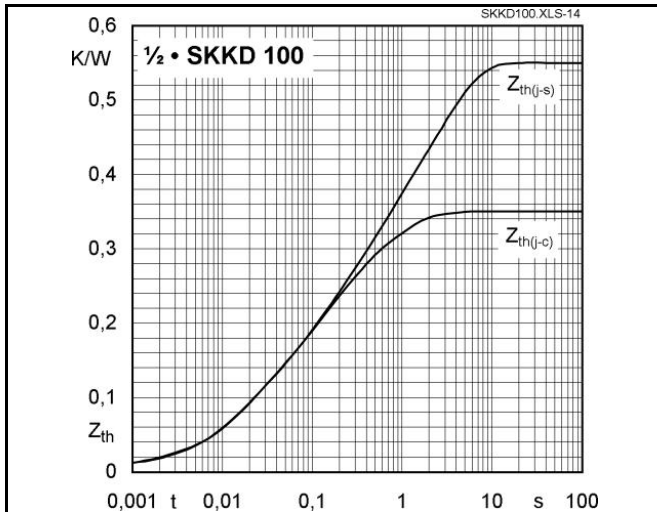


Fig. 14 Transient thermal impedance vs. time

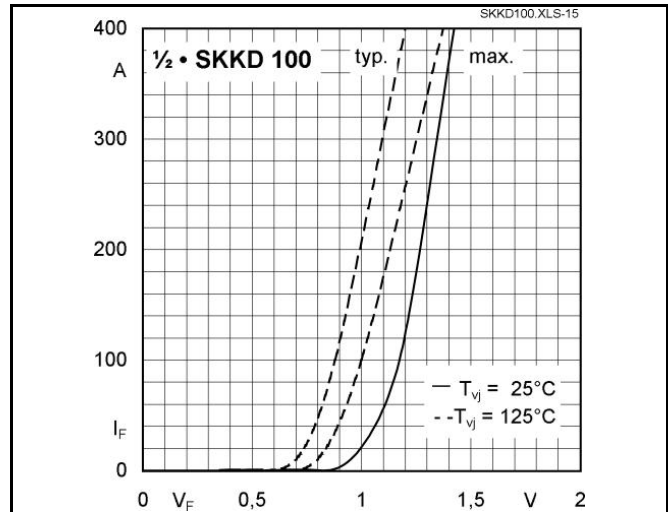


Fig. 15 Forward characteristics

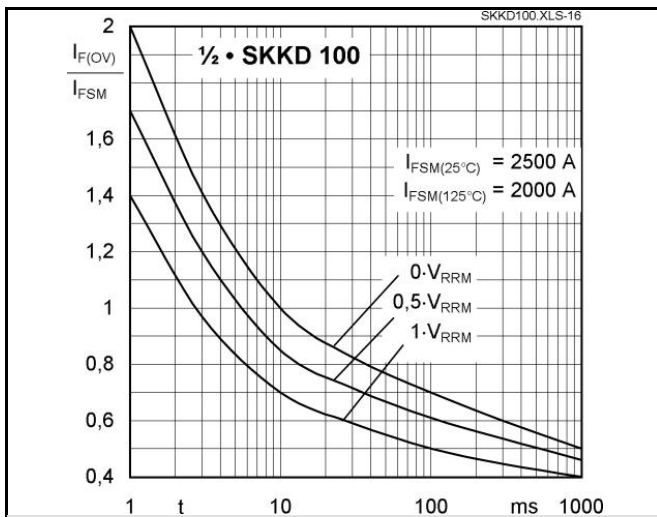
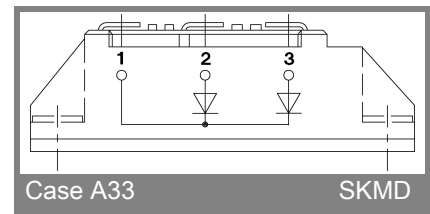
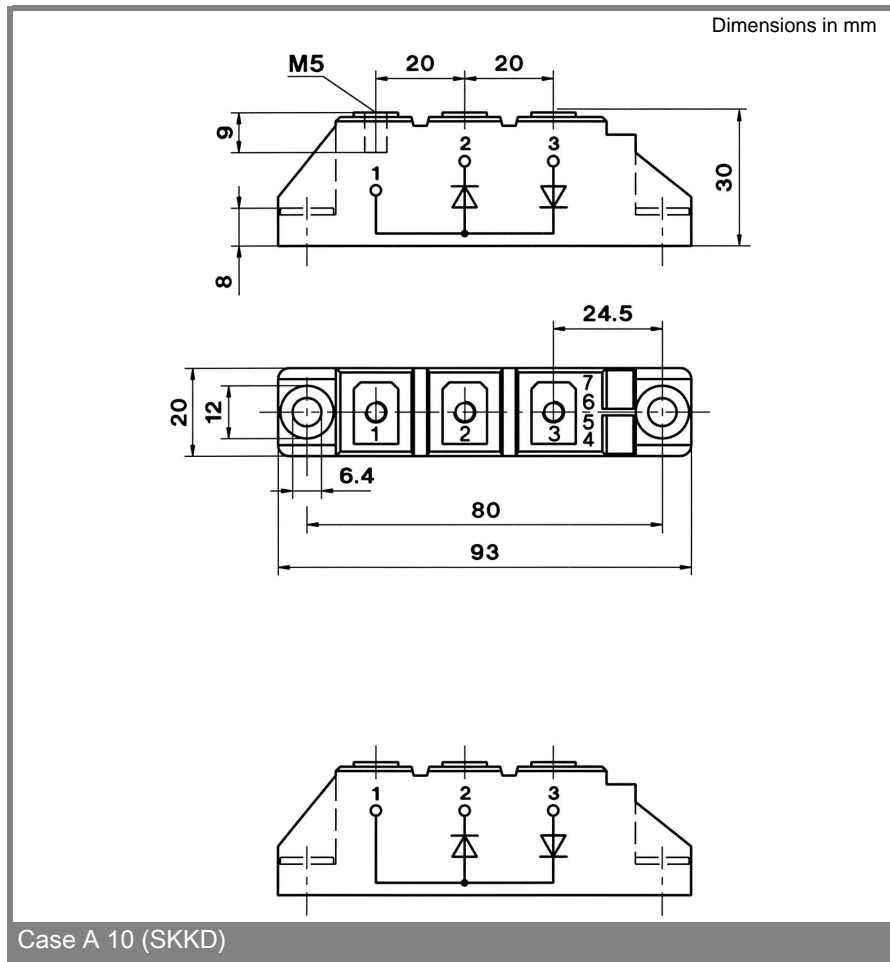


Fig. 16 Surge overload current vs. time

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